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# FPAM50LH60

## PFC SPM<sup>®</sup> 2 Series for 2-Phase Interleaved PFC

### Features

- UL Certified No.E209024 (UL1557)
- 600 V - 50 A 2-Phase Interleaved PFC with Integral Gate Driver and Protection
- Very Low Thermal Resistance Using Al<sub>2</sub>O<sub>3</sub> DBC Substrate
- Full-Wave Bridge Rectifier and High-Performance Output Diode
- Optimized for 20kHz Switching Frequency
- Built-in NTC Thermistor for Temperature Monitoring
- Isolation Rating: 2500 V<sub>rms</sub>/min

### Applications

- 2-Phase Interleaved PFC Converter

### General Description

The FPAM50LH60 is a PFC SPM<sup>®</sup> 2 module providing a fully-featured, high-performance Interleaved PFC (Power Factor Correction) input power stage for consumer, medical, and industrial applications. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockout, over-current shutdown, thermal monitoring, and fault reporting. These modules also feature a full-wave rectifier and high-performance output diodes for additional space savings and mounting convenience.

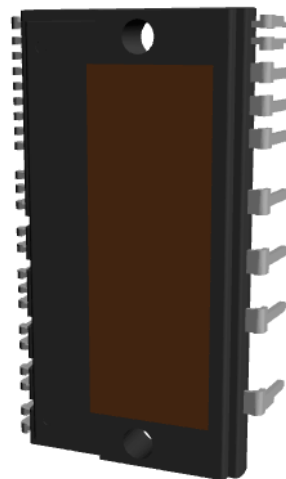


Fig. 1. 3D Package Drawing  
(Click to Activate 3D Content)

### Package Marking and Ordering Information

Device	Device Marking	Package	Packing Type	Quantity
FPAM50LH60	FPAM50LH60	S32EA-032	Rail	8

### Integrated Drive, Protection and System Control Functions

- For IGBTs: gate drive circuit, Over-Current Protection (OCP), control supply circuit Under-Voltage Lock-Out (UVLO) Protection
- Fault signal: corresponding to OC and UV fault
- Built-in thermistor: temperature monitoring
- Input interface : active-HIGH interface, works with 3.3 / 5 V logic, Schmitt trigger input

### Pin Configuration

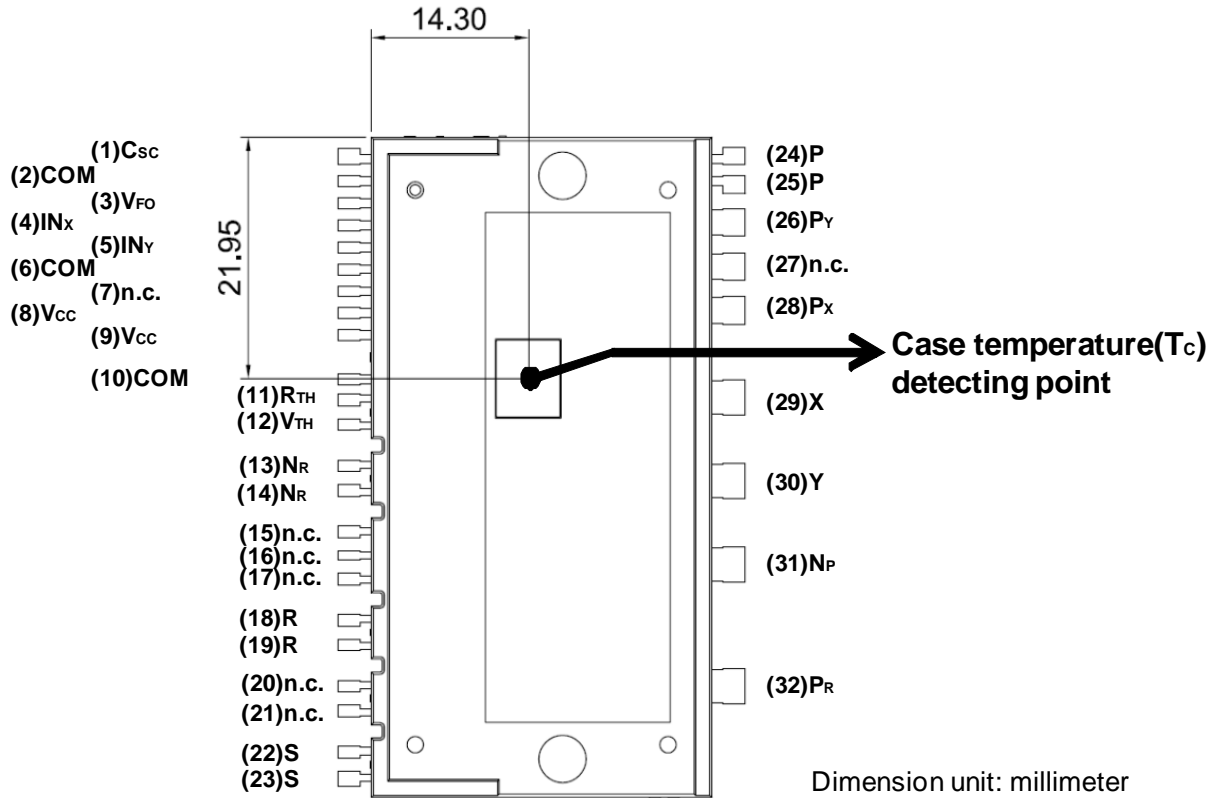


Figure 2. Top View

## Pin Descriptions

Pin Number	Pin Name	Pin Description
1	C <sub>SC</sub>	Signal Input for Over-Current Detection
2,6,10	COM	Common Supply Ground
3	V <sub>FO</sub>	Fault Output
4	IN <sub>X</sub>	PWM Input for X IGBT Drive
5	IN <sub>Y</sub>	PWM Input for Y IGBT Drive
7	N.C	No Connection
8,9	V <sub>CC</sub>	Common Supply Voltage of IC for IGBT Drive
11	R <sub>TH</sub>	Series Resistor for The Use of Thermistor
12	V <sub>TH</sub>	Thermistor Bias Voltage
13,14	N <sub>R</sub>	Negative DC-Link of Rectifier Diode
15,16,17	N.C	No Connection
18,19	R	AC Input for R-Phase
20,21	N.C	No Connection
22,23	S	AC Input for S-Phase
24,25	P	Output of Diode
26	P <sub>Y</sub>	Input of Diode
27	N.C	No Connection
28	P <sub>X</sub>	Input of Diode
29	X	Output of X Phase IGBT
30	Y	Output of Y Phase IGBT
31	N <sub>P</sub>	Negative DC-Link of IGBT
32	P <sub>R</sub>	Positive DC-Link of Rectifier Diode

## Internal Equivalent Circuit

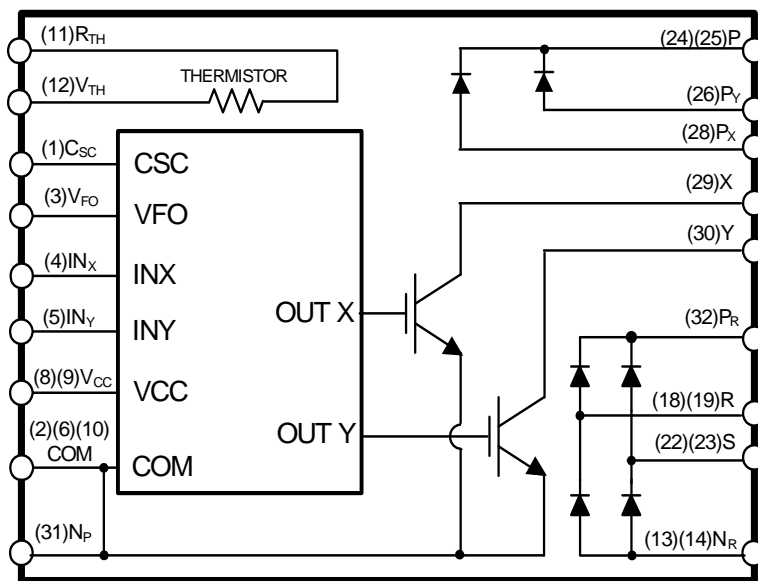


Figure 3. Internal Block Diagram

## Absolute Maximum Ratings (T<sub>J</sub> = 25°C, unless otherwise specified.)

### Converter Part

Symbol	Parameter	Conditions	Rating	Unit
V <sub>i</sub>	Input Supply Voltage	Applied between R - S	264	V <sub>rms</sub>
V <sub>PN</sub>	Output Voltage	Applied between X - N <sub>P</sub> , Y - N <sub>P</sub> , P - P <sub>X</sub> , P - P <sub>Y</sub>	450	V
V <sub>PN(Surge)</sub>	Output Supply Voltage (Surge)	Applied between X - N <sub>P</sub> , Y - N <sub>P</sub> , P - P <sub>X</sub> , P - P <sub>Y</sub>	500	V
V <sub>CES</sub>	Collector-emitter Voltage	Breakdown Voltage between X - N <sub>P</sub> , Y - N <sub>P</sub>	600	V
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage of FRD	Breakdown Voltage between P - P <sub>X</sub> , P - P <sub>Y</sub>	600	V
V <sub>RRMR</sub>	Repetitive Peak Reverse Voltage of Rectifier	Breakdown Voltage between P <sub>R</sub> - R, P <sub>R</sub> - S, R - N <sub>R</sub> , S - N <sub>R</sub>	900	V
*I <sub>F</sub>	FRD Forward Current	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C	50	A
*I <sub>FSM</sub>	Peak Surge Current of FRD	Non-Repetitive, 60 Hz Single Half-Sine Wave	500	A
*I <sub>FR</sub>	Rectified Forward Current	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C	50	A
*I <sub>FSMR</sub>	Peak Surge Current of Rectifier	Non-Repetitive, 60 Hz Single Half-Sine Wave	500	A
± *I <sub>C</sub>	Each IGBT Collector Current	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C	50	A
± *I <sub>CP</sub>	Each IGBT Collector Current(Peak)	T <sub>C</sub> = 25°C, T <sub>J</sub> < 125°C, Under 1 ms Pulse Width	100	A
*P <sub>C</sub>	Collector Dissipation	T <sub>C</sub> = 25°C per IGBT	135	W
T <sub>J</sub>	Operating Junction Temperature	(1st Note 1)	-40 ~ 125	°C

#### 1st Notes:

1. The maximum junction temperature rating of the power chips integrated within the PFC SPM® product is 125°C.
2. Marking "\*" is calculation value or design factor.

### Control Part

Symbol	Parameter	Conditions	Rating	Unit
V <sub>CC</sub>	Control Supply Voltage	Applied between V <sub>CC</sub> - COM	20	V
V <sub>IN</sub>	Input Signal Voltage	Applied between IN <sub>X</sub> , IN <sub>Y</sub> - COM	-0.3 ~ V <sub>CC</sub> + 0.3	V
V <sub>FO</sub>	Fault Output Supply Voltage	Applied between V <sub>FO</sub> - COM	-0.3 ~ V <sub>CC</sub> + 0.3	V
I <sub>FO</sub>	Fault Output Current	Sink Current at V <sub>FO</sub> Pin	1	mA
V <sub>SC</sub>	Current Sensing Input Voltage	Applied between C <sub>SC</sub> - COM	-0.3 ~ V <sub>CC</sub> + 0.3	V

### Total System

Symbol	Parameter	Conditions	Rating	Unit
T <sub>STG</sub>	Storage Temperature		-40 ~ 125	°C
V <sub>ISO</sub>	Isolation Voltage	60 Hz, Sinusoidal, AC 1 Minute, Connect Pins to Heat-Sink Plate	2500	V <sub>rms</sub>

### Thermal Resistance

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
R <sub>th(j-c)Q</sub>	Junction to Case Thermal Resistance	Each IGBT under Operating Condition	-	-	0.74	°C/W
R <sub>th(j-c)D</sub>		Each Diode under Operating Condition	-	-	1.13	°C/W
R <sub>th(j-c)R</sub>		Each Rectifier under Operating Condition	-	-	0.74	°C/W

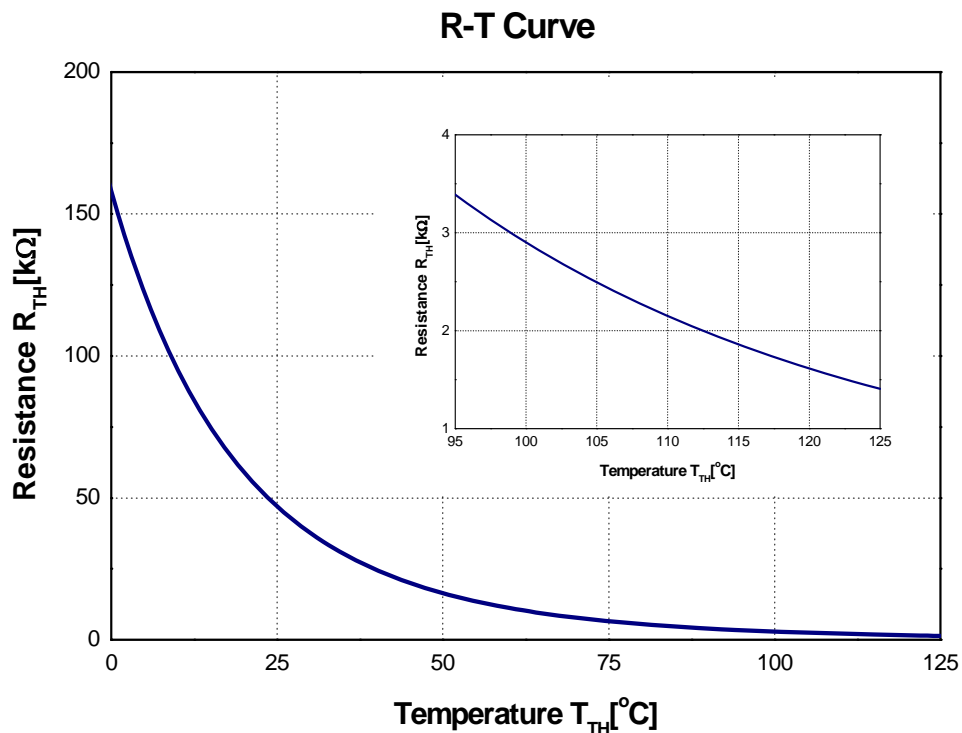


**Control Part**

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$I_{OCC}$	Quiescent $V_{CC}$ Supply Current	$V_{CC} = 15\text{ V}$ , $IN_X$ , $IN_Y - COM = 0\text{ V}$ , Supply current between $V_{CC}$ and COM	-	-	2.65	mA
$I_{PCC}$	Operating $V_{CC}$ Supply Current	$V_{CC} = 15\text{ V}$ , $f_{PWM} = 20\text{ kHz}$ , Duty = 50% Applied to One PWM Signal Input per IGBT Supply Current between $V_{CC}$ and COM	-	-	7.0	mA
$V_{FOH}$	Fault Output Voltage	$V_{SC} = 0\text{ V}$ , $V_{FO}$ Circuit: 10 k $\Omega$ to 5 V Pull-up	4.5	-	-	V
$V_{FOL}$		$V_{SC} = 1\text{ V}$ , $V_{FO}$ Circuit: 10 k $\Omega$ to 5 V Pull-up	-	-	0.5	V
$V_{SC(Ref)}$	Over-Current Protection Trip Level Voltage of CSC Pin	$V_{CC} = 15\text{ V}$	0.45	0.5	0.55	V
$UV_{CCD}$	Supply Circuit Under-Voltage Protection	Detection Level	10.5	-	13.0	V
$UV_{CCR}$		Reset Level	11.0	-	13.5	V
$t_{FOD}$	Fault-Out Pulse Width		30	-	-	$\mu\text{s}$
$V_{IN(ON)}$	ON Threshold Voltage	Applied between $IN_X$ , $IN_Y - COM$	2.6	-	-	V
$V_{IN(OFF)}$	OFF Threshold Voltage	Applied between $IN_X$ , $IN_Y - COM$	-	-	0.8	V
$R_{TH}$	Resistance of Thermistor	at $T_{TH} = 25^\circ\text{C}$ (1st Note 4, Figure 5)	-	47	-	k $\Omega$
		at $T_{TH} = 100^\circ\text{C}$ (1st Note 4, Figure 5)	-	2.9	-	k $\Omega$

**1st Notes:**

4.  $T_{TH}$  is the temperature of thermister itself. To know case temperature ( $T_C$ ), please make the experiment considering your application.



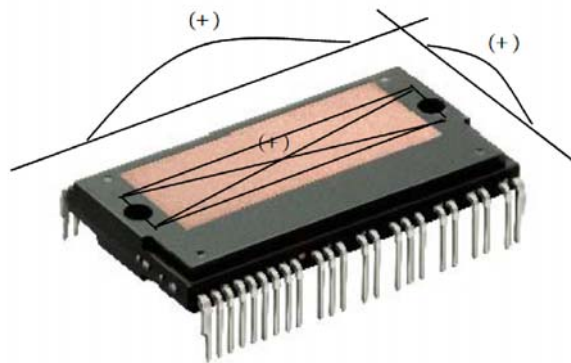
**Figure 5. R-T Curve of The Built-in Thermistor**

**Recommended Operating Conditions** ( $T_J = 25^\circ\text{C}$ , unless otherwise specified.)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$V_i$	Input Supply Voltage	Applied between R - S	187	-	253	$V_{rms}$
$I_i$	Input Current	$T_C < 100^\circ\text{C}$ , $V_i = 220\text{ V}$ , $V_O = 360\text{ V}$ , $f_{PWM} = 20\text{ kHz}$ per IGBT	-	-	35	$A_{rms}$
$V_{PN}$	Supply Voltage	Applied between X - N <sub>P</sub> , Y - N <sub>P</sub> , P - P <sub>X</sub> , P - P <sub>Y</sub>	-	-	400	V
$V_{CC}$	Control Supply Voltage	Applied between $V_{CC}$ - COM	13.5	15.0	16.5	V
$dV_{CC}/dt$	Supply Variation		-1	-	1	$V/\mu\text{s}$
$I_{FO}$	Fault Output Current	Sink Current at $V_{FO}$ Pin	-	-	1	mA
$f_{PWM}$	PWM Input Frequency	$-40^\circ\text{C} < T_J < 125^\circ\text{C}$ per IGBT	-	20	-	kHz

**Mechanical Characteristics and Ratings**

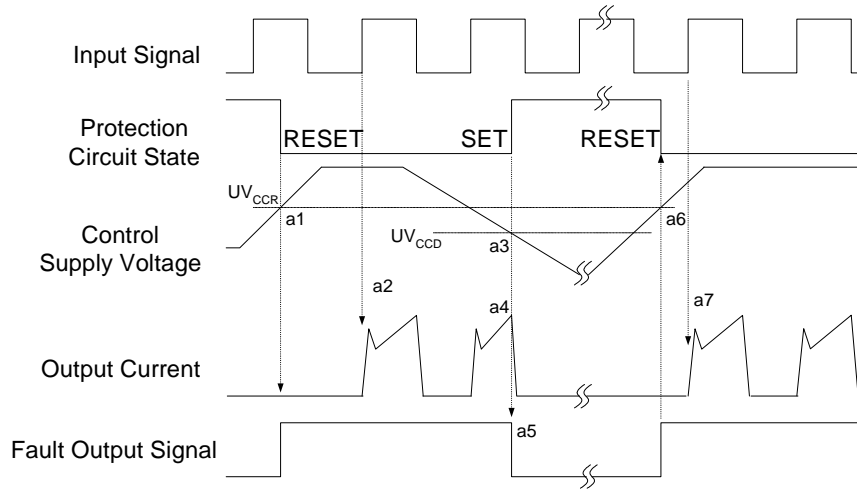
Parameter	Conditions		Min.	Typ.	Max.	Unit
Mounting Torque	Mounting Screw: M4	Recommended 0.98 N•m	0.78	0.98	1.17	N•m
		Recommended 10 kg•cm	8	10	12	kg•cm
Device Flatness	See Figure 6		0	-	+150	$\mu\text{m}$
Weight			-	32	-	g



**Figure 6. Flatness Measurement Position**

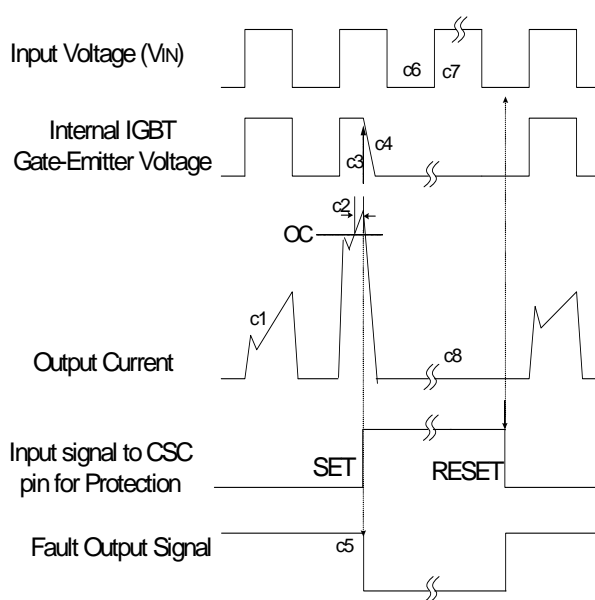


### Time Charts of Protective Function



- a1 : Control supply voltage rises: after the voltage rises  $UV_{CCR}$ , the circuits start to operate when the next input is applied.
- a2 : Normal operation: IGBT ON and carrying current.
- a3 : Under-voltage detection ( $UV_{CCD}$ ).
- a4 : IGBT OFF in spite of control input condition.
- a5 : Fault output operation starts.
- a6 : Under-voltage reset ( $UV_{CCR}$ ).
- a7 : Normal operation: IGBT ON and carrying current.

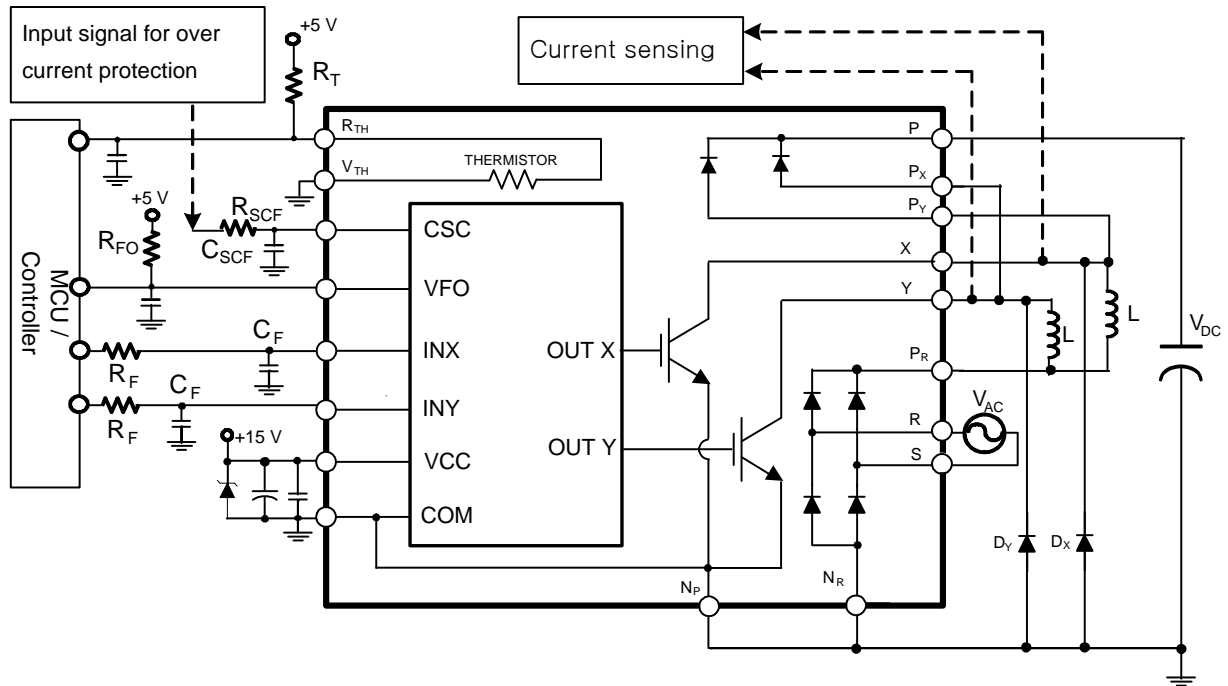
**Figure 7. Under-Voltage Protection**



(with the external over current detection circuit)

- c1 : Normal operation: IGBT ON and carrying current.
- c2 : Over-current detection (OC trigger).
- c3 : Hard IGBT gate interrupt.
- c4 : IGBT turns OFF.
- c5 : Fault output timer operation starts.
- c6 : Input "LOW": IGBT OFF state.
- c7 : Input "HIGH": IGBT ON state, but during the active period of fault output the IGBT doesn't turn ON.
- c8 : IGBT OFF state.

**Figure 8. Over-Current Protection**

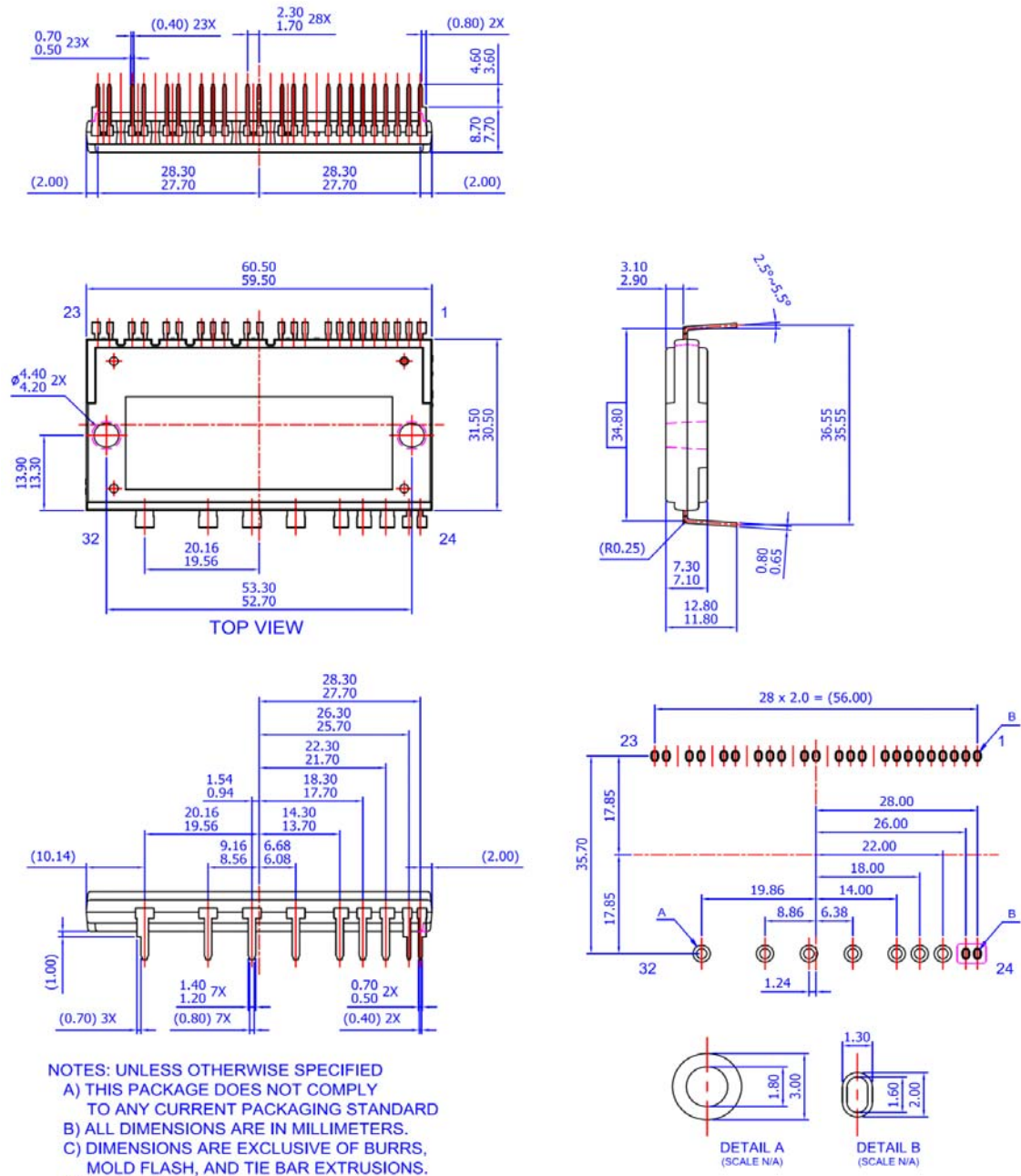


**Figure 9. Typical Application Circuit**

**2nd Notes:**

1. To avoid malfunction, the wiring of each input should be as short as possible (less than 2 ~ 3 cm).
2.  $V_{FO}$  output is open-drain type. This signal line should be pulled up to the positive-side of the MCU or control power supply with a resistor that makes  $I_{FO}$  up to 1 mA.
3. Input signal is active-HIGH type. There is a 5 k $\Omega$  resistor inside the IC to pull-down each input signal line to GND. RC coupling circuits is recommended for the prevention of input signal oscillation.  $R_F C_F$  constant should be selected in the range 50-150ns (recommended  $R_F = 100 \Omega$ ,  $C_F = 1 \text{ nF}$ ).
4. To prevent error of the protection function, the wiring related with  $R_{SCF}$  and  $C_{SCF}$  should be as short as possible.
5. In the over current protection circuit, please select the  $R_{SCF}$ ,  $C_{SCF}$  time constant in the range 1.5 ~ 2  $\mu\text{s}$ .
6. Each capacitors should be mounted as close to the PFC SPM® product pins as possible.
7. Relays are used at almost every systems of electrical equipments of home appliances. In these cases, there should be sufficient distance between the MCU / controller and the relays.
8. Internal NTC thermistor can be used for monitoring of the case temperature and protecting the device from the overheating operation. Select an appropriate resistor  $R_T$  according to the application.
9. It is recommended that anti-parallel diode ( $D_X$ ,  $D_Y$ ) be connected with each IGBT.

### Detailed Package Outline Drawings



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Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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